



# P-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (mA)			
	1.2 at V <sub>GS</sub> = - 4.5 V	- 350			
- 20	1.6 at V <sub>GS</sub> = - 2.5 V	- 300			
	2.7 at V <sub>GS</sub> = - 1.8 V	- 150			

# SC-75A or SC-89

SC-75A (SOT-416): Si1013R - Marking Code D SC-89 (SOT-490): Si1013X - Marking Code B

#### **Ordering Information:**

Si1013R-T1-GE3 (SC-75A, Lead (Pb)-free and Halogen-free) Si1013X-T1-GE3 (SC-89, Lead (Pb)-free and Halogen-free)

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- High-Side Switching
- Low On-Resistance: 1.2 Ω
  Low Threshold: 0.8 V (Typ.)
- Fast Switching Speed: 14 ns
- 1.8 V Operation
- TrenchFET<sup>®</sup> Power MOSFETs
- 2000 V ESD Protection
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- · Battery Operated Systems
- Power Supply Converter Circuits
- · Load/Power Switching Cell Phones, Pagers

#### **BENEFITS**

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		$V_{DS}$	- 20		V
Gate-Source Voltage		$V_{GS}$	± 6		V
Continuous Drain Current (T <sub>.I</sub> = 150 °C) <sup>b</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 400	- 350	
Continuous Drain Current (1 <sub>J</sub> = 150 °C)	T <sub>A</sub> = 85 °C		- 300	- 275	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	- 1000		mA mA
Continuous Source Current (Diode Conduction) <sup>b</sup>	I <sub>S</sub>	- 275	- 250		
Mariana Barra Birainatianh (an 00 75	T <sub>A</sub> = 25 °C	P <sub>D</sub>	175	150	mW
Maximum Power Dissipation <sup>b</sup> for SC-75	T <sub>A</sub> = 85 °C		90	80	
Mariana Barra Birainatianh (an 00 00	T <sub>A</sub> = 25 °C		275	250	
Maximum Power Dissipation <sup>b</sup> for SC-89	T <sub>A</sub> = 85 °C		160	140	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V

#### Notes

- a. Pulse width limited by maximum junction temperature.
- b. Surface mounted on FR4 board.

ROHS COMPLIANT HALOGEN FREE



SPECIFICATIONS (T <sub>A</sub> = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.45			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		± 1	± 2	μΑ	
Zero Gate Voltage Drain Current		V <sub>DS</sub> = - 16 V, V <sub>GS</sub> = 0 V		- 0.3	- 100	nA	
	I <sub>DSS</sub>	V <sub>DS</sub> = - 16 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 85 °C			- 5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = - 5 V, V <sub>GS</sub> = - 4.5 V	- 700			mA	
Davis Occurs On Otata		$V_{GS} = -4.5 \text{ V}, I_D = -350 \text{ mA}$		0.8	1.2		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -300 \text{ mA}$		1.2	1.6	Ω	
nesistance		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 150 mA		1.8	2.7		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 250 mA		0.4		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 150 mA, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			1500			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -250 \text{ mA}$		150		рC	
Gate-Drain Charge	$Q_{gd}$			450		1	
Turn-On Delay Time	t <sub>d(on)</sub>			5			
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 10 V, $R_L$ = 47 $\Omega$		9		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 200 mA, $V_{GEN}$ = - 4.5 V, $R_g$ = 10 $\Omega$		35			
Fall Time	t <sub>f</sub>			11		1	

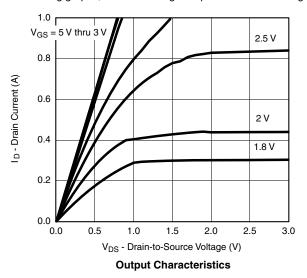
#### Notes

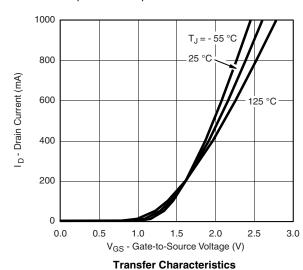
- a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

For the following graphs, P-Channel negative polarities for all voltage and current values are represented as positive values.

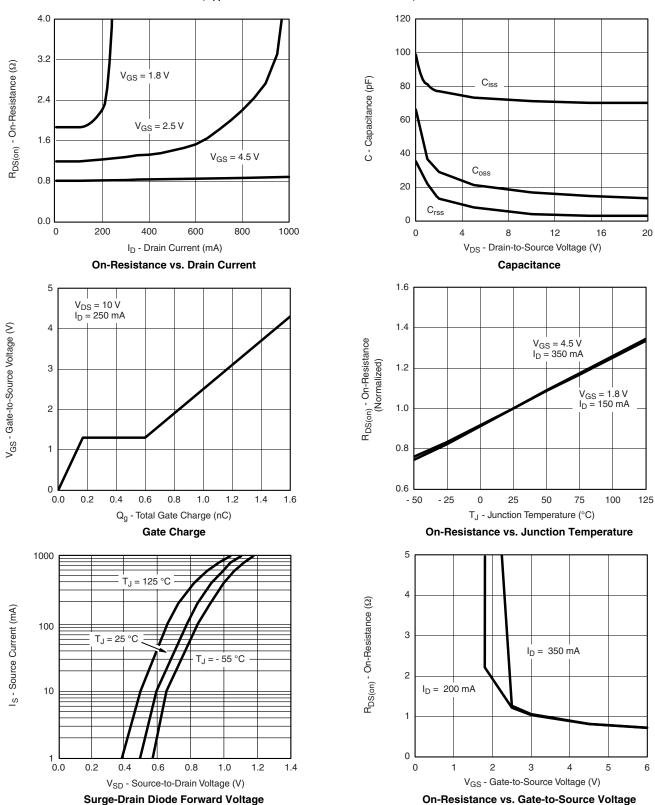






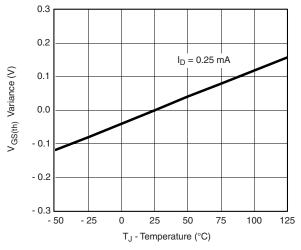


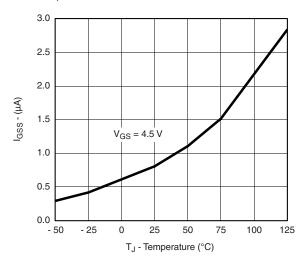
# TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



# VISHAY.

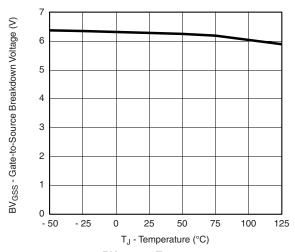
# **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



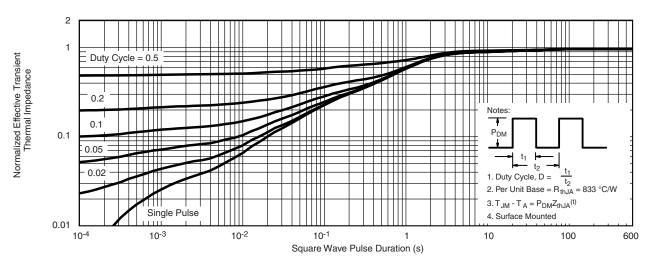


Threshold Voltage Variance vs. Temperature

 $I_{\mbox{\footnotesize GSS}}$  vs. Temperature



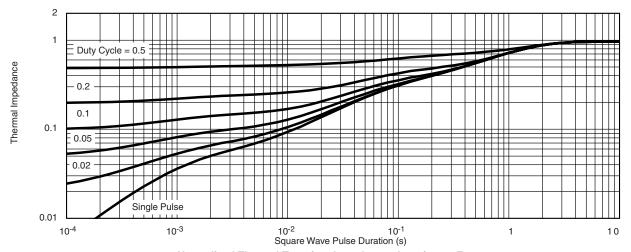
 ${\sf BV}_{\sf GSS}$  vs. Temperature



Normalized Thermal Transient Impedance, Junction-to-Ambient (SC-75A)



# **TYPICAL CHARACTERISTICS** ( $T_A = 25$ °C, unless otherwise noted)

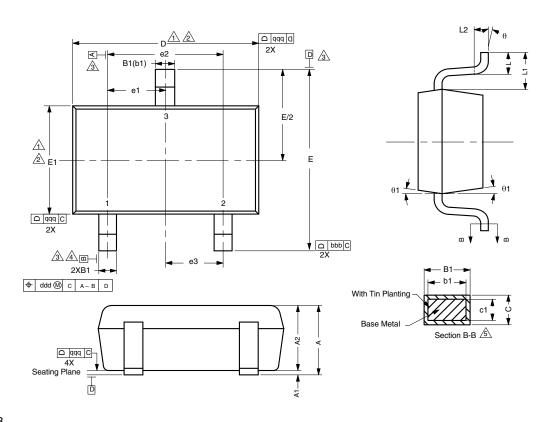


Normalized Thermal Transient Impedance, Junction-to-Foot

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# SC-75A: 3 Leads



DWG: 5868

#### **Notes**

Dimensions in millimeters will govern.

1 Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.

2. Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interelead flash, but including any mismatch between the top and bottom of the plastic body.

Datums A, B and D to be determined 0.10 mm from the lead tip.

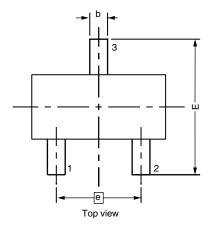
A Terminal positions are shown for reference only.

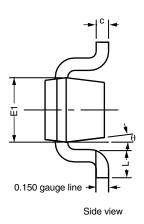
These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

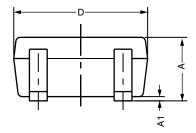
DIMENSIONS	TOLERANCES		
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.10		

DIM.	N			
Dilvi.	MIN.	NOM.	MAX.	NOTE
Α	-	-	0.80	
A <sub>1</sub>	0.00	-	0.10	
A <sub>2</sub>	0.65	0.70	0.80	
B <sub>1</sub>	0.19	-	0.24	5
b <sub>1</sub>	0.17	-	0.21	
С	0.13	-	0.15	5
C <sub>1</sub>	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
E	1.50	1.60	1.70	
E <sub>1</sub>	0.66	0.76	0.86	1, 2
e <sub>1</sub>		0.50 BSC		
e <sub>2</sub>		1.00 BSC		
e <sub>3</sub>	0.50 BSC			
L	0.15	0.205	0.30	
L <sub>1</sub>	0.40 ref.			
L <sub>2</sub>	0.15 BSC			
θ	0°	-	8°	
θ <sub>1</sub>	4°	-	10°	

### For Samsung only







#### Notes

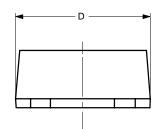
- (1) Millimeters will govern.
- (2) Dimension exclusive of mold gate burrs.
- (3) Dimension exclusive of mold flash and cutting burrs.

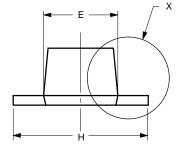
DIM.	MILLIMETERS			INCHES			
Dilvi.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.60	0.70	0.80	0.024	0.028	0.031	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
b	0.18	0.22	0.32	0.007	0.009	0.013	
С	0.11	0.13	0.21	0.004	0.005	0.008	
D	1.48	1.58	1.68	0.058	0.062	0.066	
E	1.50	1.60	1.70	0.059	0.063	0.067	
E1	0.66	0.76	0.86	0.026	0.030	0.034	
е	0.95	1.00	1.05	0.037	0.039	0.041	
L	0.22	0.32	0.42	0.009	0.013	0.017	
θ	4°	7°	10°	4°	7°	10°	

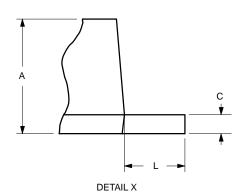




### SC89-3





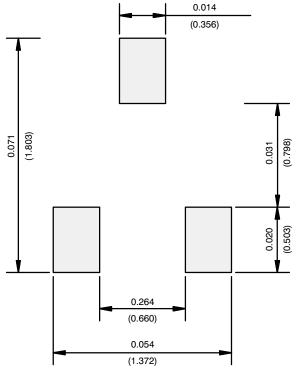


**MILLIMETERS INCHES** Dim Min Max Min Max 0.60 0.80 0.024 0.031 Α 0.23 0.33 0.009 0.013 b С 0.10 0.20 0.004 0.008 1.50 0.067 D 1.70 0.059 Ε 0.75 0.95 0.030 0.037 1.00 BSC 0.040 BSC е 0.50 BSC 0.020 BSC e<sub>1</sub> Н 1.50 0.059 0.067 0.30 0.012 0.020 L 0.50

ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5869



### **RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead**



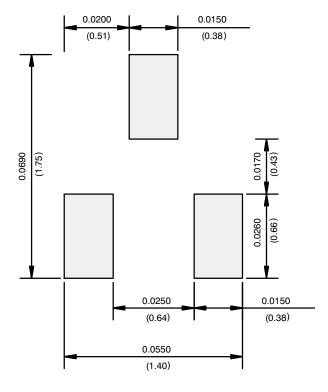
Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

APPLICATION NOTE



### **RECOMMENDED MINIMUM PADS FOR SC-89: 3-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

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